Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002-3) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- Side-wettable flanks for optical solder inspection
- Thermally efficient package in a small form factor (3.3 mm x 3.3 mm footprint)
- AEC-Q101 qualified

3. Applications

- · Reverse polarity protection
- High-speed line driver
- · High-side load switch
- Relay driver

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	-30	V
V _{GS}	gate-source voltage	T _j = 25 °C		-20	-	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-	-82	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	-	94	W
Static chara	cteristics		'		'		'
R_{DSon}	drain-source on-state resistance	$V_{GS} = -10 \text{ V}; I_D = -12 \text{ A}; T_j = 25 \text{ °C}$		-	6.5	8.2	mΩ



5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	1 2 3 4	
2	S	source	<u> </u>	D
3	S	source		
4	G	gate		$_{G}$
5	D	drain		
6	D	drain		S
7	D	drain	8 7 6 5	017aaa094
8	D	drain	MLPAK33 (SOT8002-3)	

6. Ordering information

Table 3. Ordering information

Type number			
	Name	Description	Version
BUK6Q8R2-30P	MLPAK33	plastic thermal enhanced surface mounted package with side-wettable flanks (SWF); mini leads; 8 terminals;pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-3

7. Marking

Table 4. Marking codes

Type number	Marking code
BUK6Q8R2-30P	NXB

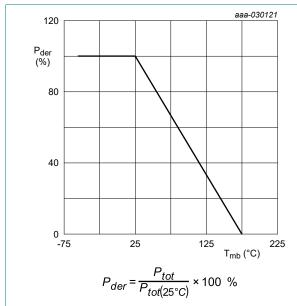
8. Limiting values

Table 5. Limiting values

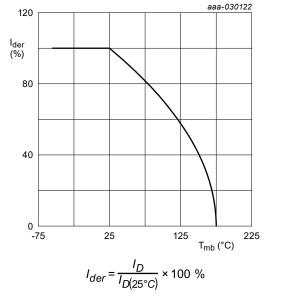
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-30	V
V _{GS}	gate-source voltage	T _j = 25 °C		-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{mb} = 25 °C		-	-82	Α
		V _{GS} = -10 V; T _{mb} = 100 °C		-	-58	Α
I _{DM}	peak drain current	single pulse; t _p ≤ 10 µs; T _{mb} = 25 °C		-	-328	Α
P _{tot}	total power dissipation	T _{mb} = 25 °C		-	94	W
Tj	junction temperature			-55	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C
Source-drain	n diode					_
Is	source current	T _{mb} = 25 °C		-	-82	Α
I _{SM}	peak source current	single pulse; t _p ≤ 10 µs; T _{mb} = 25 °C		-	-328	Α
Avalanche ru	uggedness		'			'
E _{DS(AL)S}	non-repetitive drain- source avalanche energy	$V_{sup} \le -30 \text{ V}; V_{GS} = -10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \text{ Ω}; I_D = -44.5 \text{ A}; unclamped$	[1] [2]	-	162	mJ
I _{AS}	non-repetitive avalanche current	T _{j(init)} = 25 °C	[3]	-	-44.5	Α

- Single-pulse avalanche rating limited by maximum junction temperature of 175 $^{\circ}\text{C}.$ Refer to application note AN10273 for further information.
- [2]
- Protected by 100% test.



Normalized total power dissipation as a function of mounting base temperature



Normalized continuous drain current as a Fig. 2. function of mounting base temperature

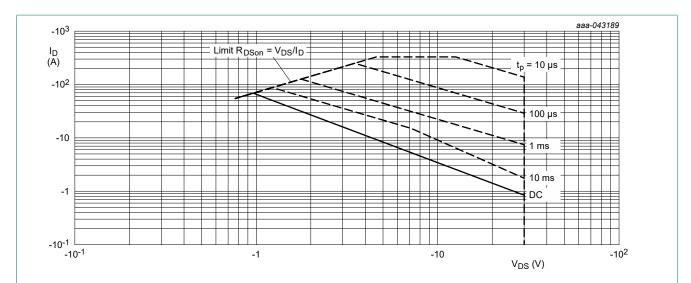


Fig. 3. Safe operating area; junction to mounting base; continuous and peak drain currents as a function of drain-source voltage

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	60	80	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base			-	1	1.6	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

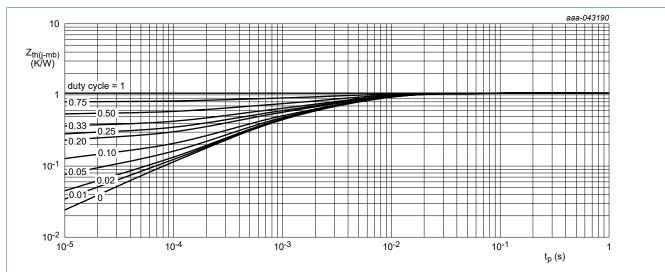


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration; typical values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-30	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-1.4	-2	-2.7	V
I _{DSS}	drain leakage current	$V_{DS} = -30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μΑ
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	$V_{GS} = -10 \text{ V}; I_D = -12 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	6.5	8.2	mΩ
	resistance	V _{GS} = -10 V; I _D = -12 A; T _j = 175 °C	-	11	14	mΩ
		$V_{GS} = -4.5 \text{ V}; I_D = -8 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	12.9	18	mΩ
9fs	forward transconductance	V_{DS} = -10 V; I_D = -30 A; T_j = 25 °C	-	80	-	S
R_G	gate resistance	f = 1 MHz	-	6	-	Ω
Dynamic ch	aracteristics		'	'		
Q _{G(tot)}	total gate charge	V_{DS} = -15 V; I_{D} = -12 A; V_{GS} = -10 V;	-	73	110	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	13	-	nC
Q _{GD}	gate-drain charge		-	17	-	nC
C _{iss}	input capacitance	V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V;	-	3800	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	440	-	pF
C _{rss}	reverse transfer capacitance		-	400	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -15 \text{ V}; I_D = -12 \text{ A}; V_{GS} = -10 \text{ V};$	-	6	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega; T_j = 25 °C$	-	18	-	ns
t _{d(off)}	turn-off delay time	1	-	91	-	ns
t _f	fall time	1	-	43	-	ns
Source-drai	in diode					
V_{SD}	source-drain voltage	$I_S = -1.9 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$	-	-0.7	-1.2	V
t _{rr}	reverse recovery time	$I_S = -1.9 \text{ A}; dI_S/dt = 100 \text{ A/µs};$	-	21	-	ns
Q _r	recovered charge	$V_{GS} = 0 \text{ V}; V_{DS} = -15 \text{ V}; T_j = 25 \text{ °C}$	-	14	_	nC

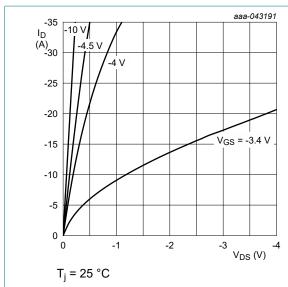


Fig. 5. Output characteristics: drain current as a function of drain-source voltage; typical values

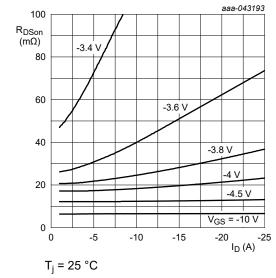


Fig. 7. Drain-source on-state resistance as a function of drain current; typical values

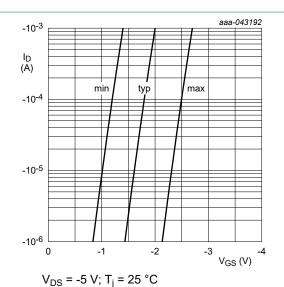


Fig. 6. Sub-threshold drain current as a function of gate-source voltage

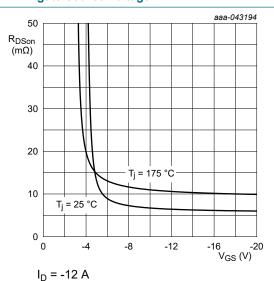


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

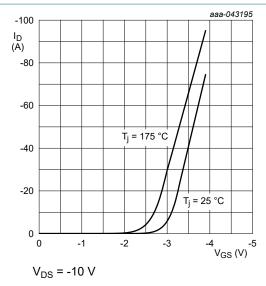


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

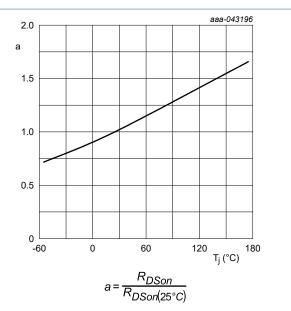


Fig. 10. Normalized drain-source on-state resistance as a function of junction temperature; typical values

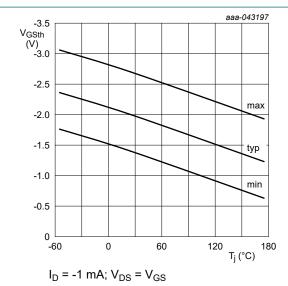
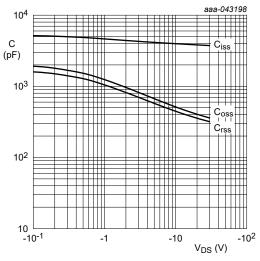


Fig. 11. Gate-source threshold voltage as a function of junction temperature



 $f = 1 MHz; V_{GS} = 0 V$

Fig. 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

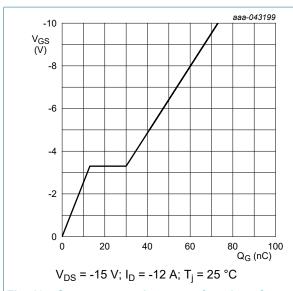


Fig. 13. Gate-source voltage as a function of gate charge; typical values

 $V_{GS} = 0 V$

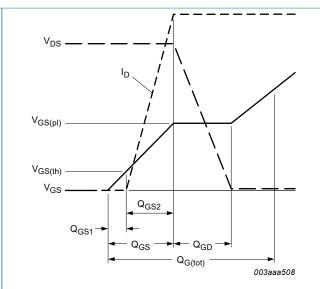


Fig. 14. Gate charge waveform definitions

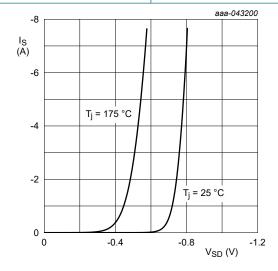
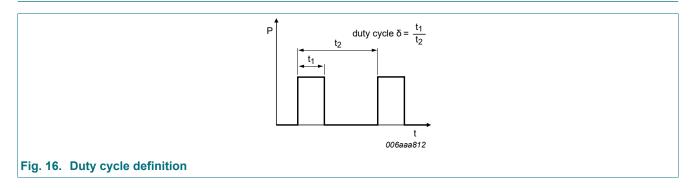


Fig. 15. Source current as a function of source-drain voltage; typical values

11. Test information



Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

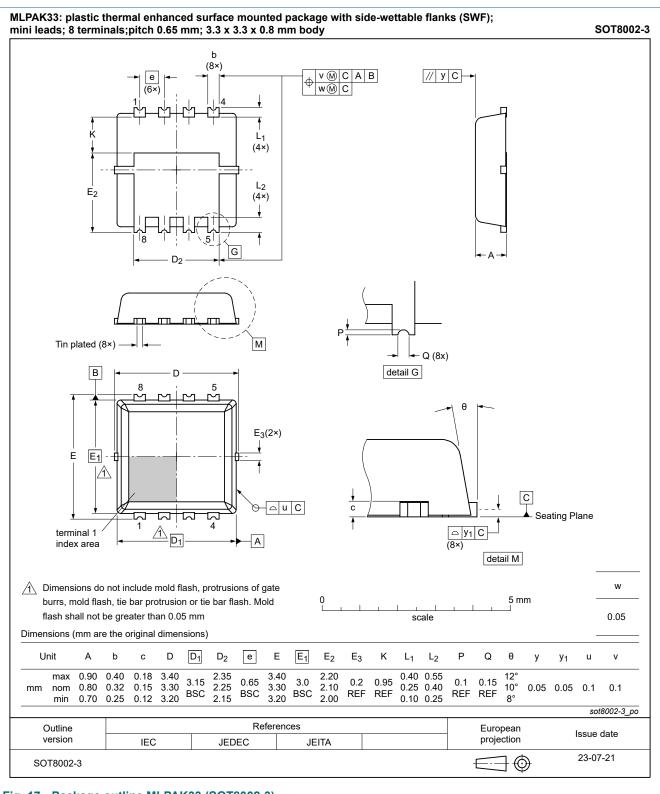
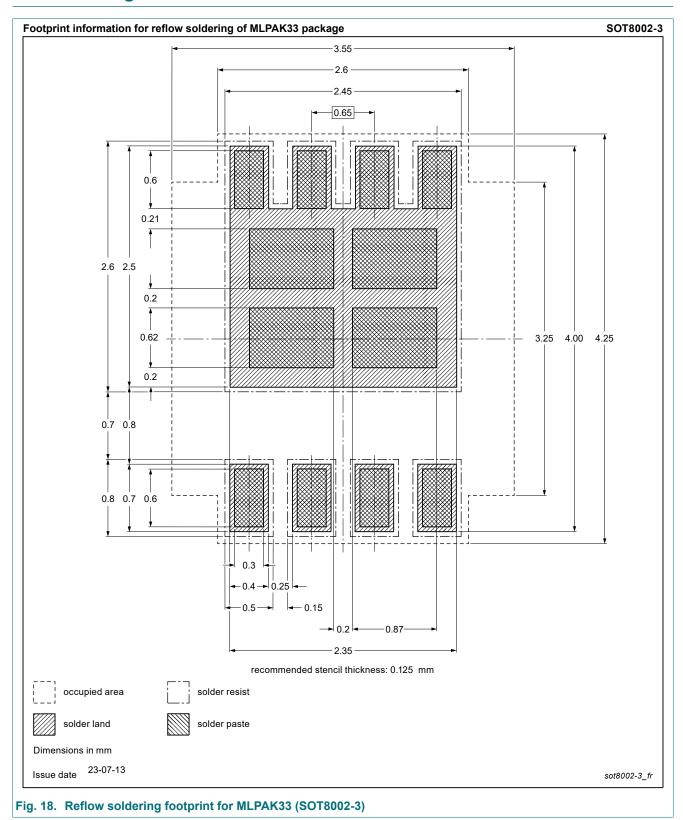


Fig. 17. Package outline MLPAK33 (SOT8002-3)

13. Soldering



14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
BUK6Q8R2-30P v.1	20250602	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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Product data sheet

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